Notice for TAIYO YUDEN products

Please read this notice before using the TAIYO YUDEN products.

REMINDERS

Product information in this catalog is as of October 2009. All of the contents specified herein are subject to change without notice due to technical improvements, etc. Therefore, please check for the latest information carefully before practical application or usage of the Products.

Please note that Taiyo Yuden Co., Ltd. shall not be responsible for any defects in products or equipment incorporating such products, which are caused under the conditions other than those specified in this catalog or individual specification.

- Please contact Taiyo Yuden Co., Ltd. for further details of product specifications as the individual specification is available.
- Please conduct validation and verification of products in actual condition of mounting and operating environment before commercial shipment of the equipment.
- All electronic components or functional modules listed in this catalog are developed, designed and intended for use in general electronics equipment.(for AV, office automation, household, office supply, information service, telecommunications, (such as mobile phone or PC) etc.). Before incorporating the components or devices into any equipment in the field such as transportation,(automotive control, train control, ship control), transportation signal, disaster prevention, medical, public information network (telephone exchange, base station) etc. which may have direct influence to harm or injure a human body, please contact Taiyo Yuden Co., Ltd. for more detail in advance. Do not incorporate the products into any equipment in fields such as aerospace, aviation, nuclear control, submarine system, military, etc. where higher safety and reliability are especially required.

In addition, even electronic components or functional modules that are used for the general electronic equipment, if the equipment or the electric circuit require high safety or reliability function or performances, a sufficient reliability evaluation check for safety shall be performed before commercial shipment and moreover, due consideration to install a protective circuit is strongly recommended at customer's design stage.

- The contents of this catalog are applicable to the products which are purchased from our sales offices or distributors (so called "TAIYO YUDEN's official sales channel").

 It is only applicable to the products purchased from any of TAIYO YUDEN's official sales channel.
- Please note that Taiyo Yuden Co., Ltd. shall have no responsibility for any controversies or disputes that may occur in connection with a third party's intellectual property rights and other related rights arising from your usage of products in this catalog. Taiyo Yuden Co., Ltd. grants no license for such rights.
- Caution for export

Certain items in this catalog may require specific procedures for export according to "Foreign Exchange and Foreign Trade Control Law" of Japan, "U.S. Export Administration Regulations", and other applicable regulations. Should you have any question or inquiry on this matter, please contact our sales staff.

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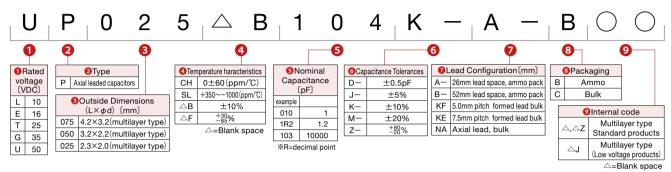
■ FEATURES

- This widely used ceramic capacitor provides a wide capacitance range of 1pF through 10μ F in one standard size and shape.
- Automatic insertion related costs are lower than with radial type capacitors.
- Mounting pitch can be between 5mm to 26mm which could be used

APPLICATIONS

• The class 1 temperature compensating (NPO) products can be used in circuits to stabilize frequency and temperature characteristics. The B, and F dielectrics are optimum for bypass capacitors.

ORDERING CODE



■ EXTERNAL DIMENSIONS/Minimum Quantity

TYPE		Dimensions		Taped product	Bulk P	roduct	Minin	num Quan	tity [PCS]		
TTPE	L	φD	φd	Straight	Straight	Formed		Bulk	Taping		
Multilayer Type 075	4.2max.	3.2max.	0.55±0.05	B [1885]		Pitch:7.5mm	Α	_	2000 (075)		
	(0.165max.)	(0.126max.)	(0.022±0.002)	B 52mm (2.05) A 26mm (1.02)	52mm (2,05) A	52mm		(0.295)	_		3000 (050)
Multilayer Type 050	3.2max.	2.2max.				NA NA	K F	В		5000 (025)	
	(0.126max.)	(0.87max.)	0.45±0.05				_		NA	1000	_
Multilayer Type 025	2.3max. (0.09max.)	2.0max. (0.079max.)	(0.018±0.002)	26mm (1.02)		Pitch: 5mm (0.197)	KE (075)	3000	_		
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	, , , , , , , , , , , , , , , , , , , ,				Unit : mm(inch)	KF (050)	3000	_		
AVAILABLE CA	APACITANCE	RANGE					KF (025)	4000	_		

AVAILABLE CAPACITANCE RANGE

7 (07 (127	DLL O	,	,,,,,,,,,,		17 11 4 0	<u> </u>																
Class 1 (Ten	perature o	compe	nsating)	_		h dielectri	c const													lultilaye	er type
WV			50V(UP)		WV				50V (UP)		3	35V(GP)	25V	(TP)		16V	(EP)		10V(LP)
Temp.c	har.	С	Н	SL		Temp.c	har.		В		F		E	3	F	В	F		3		F	F
Туре с	ар.	025	050	025		Туре с	ар.	025	050	075	025	050	050	075	075	075	025	025	050	025	050	050
[pF]	[pF:3digits]	025	050	025		[pF]	[pF:3digits]	025	050	0/5	025	050	050	0/5	0/5	0/5	025	025	050	025	030	030
1	010				_	100	101															
1.2	1R2					120	121															
1.5	1R5	L _			_	150	151	_														
1.8	1R8	-		_	-	180	181	-														
2.2	2R2		-		-	220 270	221														\vdash	
2.7 3.3	2R7 3R3	-		-	-	330	271 331	-														<u> </u>
3.9	3R9		-		-	390	391														\vdash	
4.7	4R7	-	Ì		-	470	471	-														
5.6	5R6				-	560	561															
6.8	6R8		i e		-	680	681															
8.2	8R2		İ		-	820	821															
10	100		Ì		_	1000	102							İ								
11	110					1200	122															
12	120					1500	152															
13	130					1800	182															
15	150				_	2200	222															
16	160				_	2700	272															
18	180				_	3300	332															
20	200				-	3900	392		_									_				
22	220		-		-	4700 5600	472														\vdash	
24 27	240 270		-		-	6800	562 682		-									-				-
30	300				-	8200	822		-													-
33	330				-	10000	103		-													-
36	360				-	12000	123															
39	390				-	15000	153															
43	430				-	18000	183															
47	470				-	22000	223															
51	510				_	27000	223 273							İ	İ	İ						
56	560					33000	333															
62	620					39000	393															
68	680					47000	473															
100	101				_	56000	563															
150	151	L L	<u> </u>		_	68000	683															
220	221				_	82000	823														-	
330	331		\vdash		-	100000	104		_													ļ
470	471			-	-	220000	224 474										-		-			-
680	681 102				-	470000 1000000	105															-
1000	102				-	2200000	225	-									-					-
						4700000	475	-														
						1000000	106												-			
							100															

Temperature char.	Capacitance change	Capacitance Tolerance	Q or tanδ	Class
CH	0±60ppm/℃	D(±0.5pF)		
SL	+350~-1000ppm/°C	K(±10%) J(±5%)	eng·Refer to the Part munber	1
△B	±10%	K(±10%), M(±20%)		
	+30 -85%	Z(+80/%)		2

^{*}Capacitance characteristics measured at 20°C

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Multilayer 025 Type Class 1

Rated Voltage (DC)	Ordering code	EHS (Environmental Hazardous Substances)	Temperature characteristics	Capacitance (pF)	Capacitance tolerance	Q or $ an \delta$	Insulation resistance
	UP025△010D −○ Z	RoHS		1.0			
	UP025△1R2D −○ Z	RoHS		1.2	1		
	UP025△1R5D −○ Z	RoHS		1.5			
	UP025△1R8D −○ Z	RoHS		1.8			
	UP025△2R2D−○ Z	RoHS		2.2	±0.5pF		
	UP025△2R7D − ○ Z	RoHS		2.7			
	UP025△3R3D−○ Z	RoHS		3.3 3.9 4.7			
	UP025△3R9D−○ Z	RoHS					
	UP025△4R7D − ○ Z	RoHS		4.7		Q≧400+20C	
	UP025△5R6K − ○ Z	RoHS		5.6		Q=400+20C	
	UP025△6R8K−○ Z	RoHS		6.8	±10%		10000MΩmin.
	UP025△8R2K − ○ Z	RoHS	CH	8.2			
	UP025△100J −○ Z	RoHS	SL	10			
	UP025△120J −○ Z	RoHS		12			
	UP025△150J −○ Z	RoHS	\exists	15			
50V	UP025△180J −○ Z	RoHS		18			
	UP025△220J −○ Z	RoHS		22			
	UP025△270J −○ Z	RoHS		27			
	UP025△330J −○ Z	RoHS		33			
	UP025△390J −○ Z	RoHS		39			
	UP025△470J −○ Z	RoHS		47			
	UP025△560J −○ Z	RoHS		56	±5%		
	UP025△680J −○ Z	RoHS		68			
	UP025△820J −○ Z	RoHS		82			
	UP025CH101J - ○ Z	RoHS		100		Q≧1000	
	UP025CH151J - ○ Z	RoHS		150			
	UP025CH221J - ○ Z	RoHS		220			
	UP025CH331J −○ Z	RoHS	CH	330			
	UP025CH471J −○ Z	RoHS		470			
	UP025CH681J −○ Z	RoHS		680			
	UP025CH102J - ○ Z	RoHS		1000			

[△]Please specify the temperature characteristics code and ○ lead configuration code.

Multilayer 025 Type Class 2

ated Voltage (DC)	Ordering code	EHS (Environment Hazardous Substances)	Temperature characteristics	Capacitance (pF)	Capacitance tolerance	Q or tan δ	Insulation resistance
	UP025 B101K − ○ Z	RoHS		100			
	UP025 B121K − ○ Z	RoHS		120			
	UP025 B151K −○ Z	RoHS		150			
	UP025 B181K −○ Z	RoHS		180			
	UP025 B221K − ○ Z	RoHS		220			
	UP025 B271K − ○ Z	RoHS		270			
	UP025 B331K − ○ Z	RoHS		330			
	UP025 B391K − ○ Z	RoHS		390			
	UP025 B471K − ○ Z	RoHS		470			
	UP025 B561K − ○ Z	RoHS		560			
	UP025 B681K − ○ Z	RoHS		680			
	UP025 B821K − ○ Z	RoHS		820		tan δ ≦3.5%	$5000M\Omega$ min.
50V	UP025 B102K − ○ Z	RoHS		1000			
50 V	UP025 B122K − ○ Z	RoHS		1200	±10%		
	UP025 B152K −○ Z	RoHS	В	1500			
	UP025 B222K-○ Z	RoHS		2200			
	UP025 B332K-○ Z	RoHS		3300			
	UP025 B472K − ○ Z	RoHS		4700			
	UP025 B682K-○ Z	RoHS	7	6800	1		
	UP025 B103K − ○ Z	RoHS		10000			
	UP025 B153K − ○ Z	RoHS	7	15000			
	UP025 B223K-○ Z	RoHS	7	22000			
	UP025 B333K-○ Z	RoHS		33000			
	UP025 B473K − ○ Z	RoHS	7	47000			
	UP025 B683K-○ Z	RoHS	7	68000			1000MΩmin.
	UP025 B104K − ○ Z	RoHS	7	100000		tan δ ≦5.0%	
	EP025 B224K-○Z	RoHS		220000			500MΩmin.
16V	EP025 B474K −○ Z	RoHS	7	470000	1		200MΩmin.
	EP025 B105K − ○ Z	RoHS	7	100000		tan δ ≦7.5%	100MΩmin.
	UP025 F103Z −○ Z	RoHS		10000			
501/	UP025 F223Z −○ Z	RoHS	7	22000	1	1 5 < 7.50′	4000140
50V	UP025 F473Z −○ Z	RoHS	7	47000	1	tan δ ≦7.5%	1000MΩmin.
	UP025 F104Z −○ Z	RoHS	F	100000	+80 _%		
	EP025 F224Z −○ Z	RoHS	7	220000		. 5 < 10.00	500140
16V	EP025 F474Z −○ Z	RoHS	7	470000	1	tan δ ≦10.0%	500MΩmin.
	EP025 F105Z - C Z	RoHS	7	100000	1	tan δ ≦17.5%	250MΩmin.

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PART NUMBERS

Rated Voltage (DC)	Ordering code	EHS (Environmental Hazardous Substances)	Temperature characteristics	Capacitance (pF)	Capacitance tolerance	Q or tan δ	Insulation resistance	
	EP025 B122M − ○ J	RoHS		1200				
	EP025 B152M − ○ J	RoHS		1500				
	EP025 B182M − ○ J	RoHS		1800				
	EP025 B222M-○J	RoHS		2200				
	EP025 B272M − ○ J	RoHS		2700	±20%		5000MΩmin.	
	EP025 B332M−○J	RoHS		3300				
	EP025 B392M −○ J	RoHS		3900				
16V	EP025 B472M −○ J	RoHS	В	4700		tan δ ≤3.5%		
100	FP025 B562M −○ J	RoHS]	5600		tano <u>=</u> 0.570		
	EP025 B682M −○ J	RoHS		6800				
	EP025 B822M -○ J	RoHS		8200				
	EP025 B103M -○ J	RoHS		10000				
	EP025 B123M −○ J	RoHS		12000				
	EP025 B153M −○ J	RoHS		15000				
	EP025 B183M −○ J	RoHS		18000				
	EP025 B223M −○ J	RoHS		22000				
	TP025 F103Z - J	RoHS		10000				
25V	TP025 F223Z −○ J	RoHS	F	22000		tan δ ≦7.5%	1000MΩmin.	
	TP025 F473Z −○ J	RoHS		47000				

[△]Please specify the temperature characteristics code and ○ lead configuration code.

Multilayer type Class 1

	er type Class I						
Rated Voltage (DC)	Ordering code	EHS (Environmental Hazardous Substances)	Temperature characteristics	Capacitance (pF)	Capacitance tolerance	Q or tan δ	Insulation resistance
	UP050CH220J-○ Z	RoHS		22			
*	UP050CH240J-○ Z	RoHS		24		Q≧400+20C	
	UP050CH270J-○ Z	RoHS		27			
*	UP050CH300J-○ Z	RoHS		30			
	UP050CH330J-○ Z	RoHS		33			
*	UP050CH360J-○ Z	RoHS		36			
	UP050CH390J-○ Z	RoHS		39			
*	UP050CH430J-○ Z	RoHS		43			
	UP050CH470J- ○ Z	RoHS		47			
*	UP050CH510J- ○ Z	RoHS		51			
	UP050CH560J-○ Z	RoHS		56			
*	UP050CH620J-○ Z	RoHS		62			
	UP050CH680J-○ Z	RoHS		68			
*	UP050CH750J- ○ Z	RoHS		75			
*	UP050CH820J-○ Z	RoHS		82			
*	UP050CH910J- ○ Z	RoHS		91			
	UP050CH101J- ○ Z	RoHS		100			
*	UP050CH111J- ○ Z	RoHS		110			
*	UP050CH121J- ○ Z	RoHS		120			
*	UP050CH131J- ○ Z	RoHS		130			
50V	UP050CH151J- ○ Z	RoHS	CH	150	±5%		10000MΩmin.
*	UP050CH161J- ○ Z	RoHS		160		Q≧1000	
*	UP050CH181J- ○ Z	RoHS		180		Q≦1000	
*	UP050CH201J- ○ Z	RoHS		200			
	UP050CH221J- ○ Z	RoHS		220			
*	UP050CH241J- ○ Z	RoHS		240			
*	UP050CH271J- ○ Z	RoHS		270			
*	UP050CH301J- ○ Z	RoHS		300			
	UP050CH331J- ○ Z	RoHS		330			
*	UP050CH361J- ○ Z	RoHS		360			
*	UP050CH391J- ○ Z	RoHS		390			
*	UP050CH431J- ○ Z	RoHS		430			
	UP050CH471J- ○ Z	RoHS		470			
*	UP050CH511J- ○ Z	RoHS		510			
*	UP050CH561J- ○ Z	RoHS		560			
*	UP050CH621J- ○ Z	RoHS		620			
	UP050CH681J- ○ Z	RoHS		680]		
*	UP050CH751J- ○ Z	RoHS		750			
*	UP050CH821J- ○ Z	RoHS		820			
*	UP050CH911J- ○ Z	RoHS		910			
	UP050CH102J- ○ Z	RoHS		1000			

[△]Please specify the temperature characteristics code and ○ lead configuration code.

^{★ :} Optior

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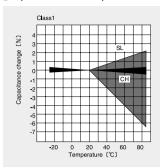
Multilayer type Class 2

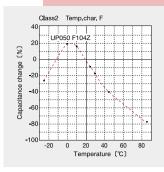
Rated Voltage (DC)	Ordering code	EHS (Environmental Hazardous Substances)	Temperature characteristics	Capacitance (pF)	Capacitance tolerance	Q or tan δ	Insulation resistance
*	UP050B122K-○Z	RoHS		1200			
	UP050B152K-○Z	RoHS	1	1500			
*	UP050B182K-○Z	RoHS		1800			
	UP050B222K-○Z	RoHS	1	2200	1		
*	UP050B272K-○Z	RoHS	1	2700			
	UP050B332K-○Z	RoHS		3300			
*	UP050B392K-○Z	RoHS	1	3900			
	UP050B472K-○Z	RoHS	1	4700			5000MΩmin.
*	UP050B562K-○Z	RoHS		5600			
	UP050B682K-○Z	RoHS	1	6800	1	tan δ ≦3.5%	
*	UP050B822K-OZ	RoHS	1	8200	1		
	UP050B103K-○Z	RoHS		10000	1		
50V ★	UP050B123K-○Z	RoHS	1	12000	1		
50V ^	UP050B153K-○Z	RoHS	1	15000	1		
*	UP050B183K-○Z	RoHS	_	18000			
	UP050B223K-○Z	RoHS	В	22000	±10%		
*	UP050B273K-○Z	RoHS	1	27000	1		
	UP050B333K-○Z	RoHS		33000			
*	UP050B393K-○Z	RoHS	1	39000			
	UP050B473K-○Z	RoHS	1	47000	1		
*	UP050B563K-OZ	RoHS	1	56000	7		1000MΩmin.
	UP050B683K-○Z	RoHS	1	68000			
*	UP050B823K-○Z	RoHS	1	82000			
	UP050B104K-○Z	RoHS	i	100000		tan δ ≦5.0%	
	UP050B224K-○Z	RoHS		220000			500MΩmir
	UP050B474K-○Z	RoHS	1	470000	1		200MΩmir
35V	GP050B105K-○Z	RoHS	i i	1000000	1		100MΩmir
	EP050B225K-○Z	RoHS		2200000		tan δ ≦7.5%	50MΩmin
16V	EP050B475K-○Z	RoHS	1	4700000			
	EP050B106K-OZ	RoHS	1	10000000		$\tan \delta \leq 12.5\%$	20MΩmin
	UP050F103Z-OZ	RoHS		10000			
	UP050F223Z-OZ	RoHS	1 1	22000	1		400
	UP050F473Z-○Z	RoHS	1 1	47000	1	tan δ ≦7.5%	1000MΩmi
50V	UP050F104Z-OZ	RoHS		100000			
	UP050F224Z-OZ	RoHS	i _ i	220000	+80%		
	UP050F474Z-OZ	RoHS	F	470000	-20 [%]	tan δ ≦10.0%	500MΩmir
	UP050F105Z-OZ	RoHS		1000000	1	. 5 < 150/	250MΩmir
16V	EP050F225Z-OZ	RoHS	1	2200000	1	tan δ ≦15%	125MΩmir
401/	LP050F475Z-OZ	RoHS	1 1	4700000	1	1 5 < 47 F2/	50MΩmin
10V	LP050F106Z-OZ	RoHS	1 1	10000000	1	tan δ ≦17.5%	25MΩmin
50V	UP075B105K-○	RoHS		1000000		tan δ ≦5.0%	100MΩmir
251/	GP075B225K-O	RoHS	1 _	2200000	1		50MΩmin
35V	GP075B475K-○	RoHS	В	4700000	±10%	tan δ ≦7.5%	
25V	TP075B106K-O	RoHS	1	10000000	1	tan δ ≦12.5%	20MΩmin.
35V	GP075F106Z-O	RoHS	F	10000000	+80 _% -20 [%]	tan δ ≦17.5%	25MΩmin
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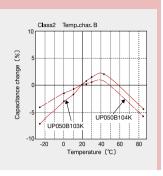
^{★ :} Option

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Capacitance -vs- Temperature Characteristics







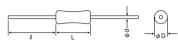
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1)Minimum Quantity

Tuna	Lood configuration code	Minim	num Quantity(PCS)
Туре	Lead configuration code	Bulk	Taping
	A-(1.024 inch wide)		2000 (075)
Multilayer	B-(2.047 inches wide)	_	3000 (050) 5000 (025)
type	NA	1000	
(075, 050, 025)	KE (075)	3000	
	KF (050)	3000	_
	KF (025)	4000	

②Dimensions of Bulk Products

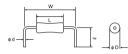
NA configuration



Tuno	Dimensions(mm)							
Type	φD	L	φd	l				
Multilayer	2.0max	2.3max	0.45±0.05	20.0min.				
type 025	(0.079)	(0.09)	(0.018±0.002)	(0.787)				
Multilayer	2.2max	3.2max	0.45±0.05	20.0min.				
type 050	(0.087)	(0.126)	(0.018±0.002)	(0.787)				
Multilayer	3.2max	4.2max	0.55±0.05	20.0min.				
type 075	(0.126)	(0.165)	(0.022±0.002)	(0.787)				

Unit: mm(inch)

KF/KE configuration

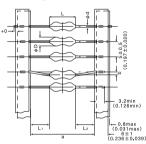


Time	リード形状記号		Dimensions (mm)							
Type	リート形仏配号	φD	L	W	φd	l				
Multilayer	KF	2.0max	2.3max	5.0±0.5	0.45±0.05	6.5±0.5				
type 025	NF.	(0.079max)	(0.09max)	(0.197±0.020)	(0.018±0.002)	(0.256±0.020)				
Multilayer	KF	2.2max	3.2max	5.0±0.5	0.45±0.05	6.5±0.5				
type 050	NF.	(0.087max)	(0.126max)	(0.197±0.020)	(0.018±0.002)	(0.256±0.020)				
Multilayer	I/E	3.2max	4.2max	7.5±0.5	0.55±0.05	6.5±0.5				
type 075	KE	(0.126max)	(0.165max)	(0.295±0.020)	(0.022±0.002)	(0.256±0.020)				

Unit: mm(inch)

3 Taping Dimensions

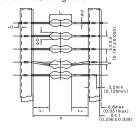
● A-(a: 1.024 inch wide) configuration



_			Dimens	Dimensions (mm)									
Type	φD	L	а	b	$ L_1-L_2 $	φd	insertion pitch						
Multilayer	2.0max	2.3max				0.45±0.05							
type 025	(0.079max)	(0.09max)	+0.5			(0.018±0.002)	5.0						
Multilayer	2.2max	3.2max	26+0.5	0.8max.	0.5max	0.45±0.05	(0.197)						
type 050	(0.087max)	(0.126max)	(1.024 ^{+0.020})	(0.031max.)	(0.020max.)	(0.018±0.002)							
Multilayer	3.2max	4.2max	((GIGG IIIIGAI)		0.55±0.05	7.5						
type 075	(0.126max)	(0.165max)				(0.022±0.002)	(0.295)						

Unit: mm(inch)

● B - (a: 2.047 inches wide) configuration



			Dimens	sions(mm)		Minimum
Туре	φD	L	а	b	L ₁ -L ₂	φd	insertion pitch
Multilayer	2.0max	2.3max				0.45±0.05	
type 025	(0.079max)	(0.09max)	+2			(0.018±0.002)	5.0
Multilayer	2.2max	3.2max	52 ⁺²	1.2max.	1.0max	0.45±0.05	(0.197)
type 050	(0.087max)	(0.126max)	(2.047+0.079)	(0.047max.)	(0.039max.)	(0.018±0.002)	
Multilayer	3.2max	4.2max	(2.011 0.000)	(Old ITTIBAL)	(Olocoman)	0.55±0.05	7.5
type 075	(0.126max)	(0.165max)				(0.022±0.002)	(0.295)
*Radial tap	ing is availa	able for 075	type (Op	tional)		Unit:	mm(inch)

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AXIAL LEAD	ED CERAMIC CAPACITORS				
1. Operating 7	Temperature Range		_		
	Temperature Compensating (Class1)	Multilayer type			
Specified		Multilayer type	05 to 1.05°0		
Value	High Permittivity (Class2)	(Characteristics : B) Multilayer type	B) —25 to +85°C		
		(Characteristics : F)			
O. O	Down and the Down and the Control of				
2. Storage lei	mperature Range Temperature Compensating (Class1)	Multilayer type			
	Temperature Compensating (Class I)	Multilayer type			
Specified /alue	High Bornstitticity (Ologon)	(Characteristics : B)	-25 to +85°C		
/aiue	High Permittivity (Class2)	Multilayer type			
		(Characteristics : F)			
3. Rated Volta	age				
	Temperature Compensating (Class1)	Multilayer type	50VDC		
Specified		Multilayer type	16VDC、25VDC、35VDC、50V	/DC	
/alue	High Permittivity (Class2)	(Characteristics : B) Multilayer type			
		(Characteristics : F)	10VDC、16VDC、25VDC、35V	/DC、50VDC	
1. Withstandir	ng Voltago				
Between term	-				
Specified					
alue	No abnorminality				
	s and Remarks]				
Applied volta	age : Rated Voltage×3 (Class 1) : Rated Voltage×2.5 (Class 2)				
Duration: 1 t	o 5 sec.				
	narge current : 50mA max. (Class 1,2)				
Between term Specified	inals and body				
alue	No abnorminality				
Test Method	s and Remarks]				
Metal globule	e method Applied voltage: Rated Voltag	e×2.5, Duration: 1 to 5 s	ec., Charge/Discharge current:	50mA max.	
. Insulation I	Resistance				
	Temperature Compensating (Class1)	Multilayer type	10000MΩmin.		
			Rated Ivoltage: 16VDC		
		Multilayer type	1200pF~22000pF(Item : △) 220000pF	: 5000MΩ min : 500MΩ min	
			470000pF	: 200MΩ min	
			1000000pF	: 100MΩ min	
			4700000pF 2200000pF	: 20MΩ min : 50MΩ min	
			1000000pF	: 20MΩ min	
			10000000pF Rated Ivoltage: 25VDC	: 20MΩ min	
			10000000pF	: 20MΩmin	
		(Characteristics : B)	Rated Ivoltage: 35VDC		
			1000000pF 2200000pF	: 100MΩ min : 50MΩ min	
			4700000pF	: 20MΩ min	
			Rated Ivoltage : 50VDC	. 5000140	
Specified			100pF~39000pF 47000pF~100000pF	: 5000MΩ min : 1000MΩ min	
/alue	High Permittivity (Class2)		220000pF	: 500MΩ min	
			470000pF 1000000pF	: 200MΩ min	
			Rated Ivoltage: 10VDC	: 100MΩ min	
			4700000pF	: 50MΩ min	
			10000000pF Rated Ivoltage: 16VDC	: 25MΩ min	
			220000pF	: 500MΩ min	
			470000pF	: 500MΩ min	
		Multilayer type	1000000pF 2200000pF	: 250MΩ min : 125MΩ min	
		(Characteristics : F)	Rated voltage : 25VDC		
			10000pF~47000pF(Item△J)	: 1000MΩ min	
			Rated voltage: 35VDC 1000000pF	: 25MΩ min	
			Rated voltage : 50VDC		
			10000pF~100000pF 220000pF~470000pF	: 1000MΩ min : 500MΩ min	
			100000pF	: 250MΩ min	
	s and Remarks]				
Applied volta	age: Rated voltage, Duration: 60±5 sec.				
. Capacitano	ce				
			±0.5pF		
	Temperature Compensating (Class1)	Multilayer type	±5% ±10%		
Specified		Multilayer type			
/alue	High Description (C)	(Characteristics : B)	±10%、±20%(Item△J)		
	High Permittivity (Class2)	Multilayer type	+80 _% -20 [%]		
	1	(Characteristics : F)	-20 ^{'0}		
	s and Remarks】 equency :1MHz±10% (Class 1:C≦1	000nF) Measuring	voltage : 1.0±0.5Vrms (Class	1 : C≦1000pF)	Bias application : None
weasuning if	: 1kHz±10% (Class 1 : C>1	000pF)	: 1.0±0.2Vrms (Class	1:C>1000pF)	ыма аррисацоп - попе
	: 1kHz±10% (Class 2 : C≦1	0μ F)	: 1.0±0.2Vrms (Class	2 : C≦10μF)	
	: 120Hz±10% (Class 2 : C>1	0μ ⊢)	: 0.5±0.1Vrms (Class	2:C>10µF)	

With standing voltage is also referred to as "voltage proof" under IEC specifications.

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7. Q or lange	ant of Loop Angle (ton 5)		
	ent of Loss Angle (tanδ)		00-F
	Temperature Compensating (Class1)	Multilayer type	30pF or under : Q≥400+20C 33pF or over : Q≥1000 C : Nominal Capacitance [pF]
Specified Value		Multilayer type (Characteristics : B)	Rated Ivoltage : 16VDC 1200pF~22000pF (Item△J) : 3.5% max 100000pF : 5.0% max 220000pF~470000pF : 5.0% max 100000pF~2200000pF : 7.5% max 470000pF~10000000pF : 12.5% max Rated Ivoltage : 25VDC 10000000pF : 12.5% max Rated Ivoltage : 35VDC 1000000pF : 5.0% max 2200000pF~4700000pF : 5.0% max 2200000pF~4700000pF : 7.5% max Rated Ivoltage : 50VDC 100pF~39000pF : 3.5% max 47000pF~1000000pF : 3.5% max 47000pF~1000000pF : 5.0% max
	High Permittivity (Class2)	Multilayer type (Characteristics : F)	Rated Ivoltage: 10VDC 4700000pF~1000000pF : 17.5% max Rated Ivoltage: 16VDC 220000pF : 10.0% max 470000pF : 10.0% max 1000000pF : 17.5% max 2200000pF : 15.0% max 2200000pF : 15.0% max Rated Ivoltage: 25VDC 10000pF~47000pF (Item△J) : 7.5% max Rated Ivoltage: 35VDC 1000000pF : 17.5% max Rated Ivoltage: 50VDC 100000pF~100000pF : 7.5% max Rated Ivoltage: 50VDC 10000pF~100000pF : 7.5% max 220000pF~470000pF : 10.0% max 1000000pF : 15.0% max
	s and Remarks] requency :1MHz±10% (Class 1 : C≦1 :1kHz±10% (Class 1 : C>1	000pF)	g voltage :1.0±0.5Vrms (Class 1 : C≦1000pF) Bias application : None :1.0±0.2Vrms (Class 1 : C>1000pF) :1.0±0.2Vrms (Class 2 : C≦10uF)
	: 1kHz±10% (Class 2 : C≦1 : 120Hz±10% (Class 2 : C>1		: 0.5±0.1Vrms (Class 2 : C>10µF)
8. Capacitano		0μF)	
	: 120Hz±10% (Class 2 : C>1	0μF)	
	: 120Hz±10% (Class 2 : C>1	0μF)	
When voltage Specified	: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate of is not applied Temperature Compensating (Class1)	0μF) f Capacitance Change	: 0.5±0.1Vrms (Class 2: C>10μF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10%
	:120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate of is not applied	OuF) f Capacitance Change Multilayer type Multilayer type	: 0.5±0.1Vrms (Class 2 : C>10µF) CH: 0±60 SL: -350~+1000 [ppm/C]
When voltage Specified Value [Test Methods Measuremen	: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate of is not applied Temperature Compensating (Class1) High Permittivity (Class2) s and Remarks]	Multilayer type (Characteristics: B) Multilayer type (Characteristics: F)	: 0.5±0.1Vrms (Class 2 : C>10µF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10%
When voltage Specified Value [Test Methods Measuremen (Ces-C20) C20×△T Change of m Temperatu Temperatu	: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate of is not applied Temperature Compensating (Class1) High Permittivity (Class2) s and Remarks] nt of capacitance at 20°C and 85°C, -25°C	Multilayer type Multilayer type (Characteristics : B) Multilayer type (Characteristics : F) shall be made to calculate o 5 (Class 2) step 4 : 85°C step 5 : 20°C	: 0.5±0.1Vrms (Class 2: C>10μF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10% +30 -85%
When voltage Specified Value [Test Methods Measuremen (C ₈₅ -C ₂₀ ×ΔT Change of m Temperatu Temperatu Temperatu	: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate or is not applied Temperature Compensating (Class1) High Permittivity (Class2) s and Remarks] to of capacitance at 20°C and 85°C, -25°C	Multilayer type Multilayer type (Characteristics : B) Multilayer type (Characteristics : F) shall be made to calculate o 5 (Class 2) step 4 : 85°C step 5 : 20°C	: 0.5±0.1Vrms (Class 2: C>10μF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10% +30 -85%
When voltage Specified Value [Test Methods Measuremen (C ₈₅ -C ₂₀) C ₂₀ ×ΔT Change of m Temperatu Temperatu Temperatu 9. Terminal St	: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate or is not applied Temperature Compensating (Class1) High Permittivity (Class2) s and Remarks] to of capacitance at 20°C and 85°C, -25°C	Multilayer type Multilayer type (Characteristics: B) Multilayer type (Characteristics: F) shall be made to calculate o 5 (Class 2) step 4:85°C step 5:20°C	: 0.5±0.1Vrms (Class 2 : C>10µF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10% +30 -85%
When voltage Specified Value [Test Methods Measuremen (C ₈₅ -C ₂₀) C ₂₀ ×ΔT Change of m Temperatu Temperatu Temperatu 9. Terminal St	: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate or is not applied Temperature Compensating (Class1) High Permittivity (Class2) s and Remarks] to f capacitance at 20°C and 85°C, -25°C	Multilayer type (Characteristics : B) Multilayer type (Characteristics : B) Multilayer type (Characteristics : F) shall be made to calculate to 5 (Class 2) step 4 : 85°C step 5 : 20°C re)	: 0.5±0.1Vrms (Class 2: C>10μF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10% +30 -85%
$\begin{tabular}{ll} When voltage \\ Specified \\ Value \\ \hline \begin{tabular}{ll} Test Methods \\ Measuremen \\ \hline \hline $(C_{85}-C_{20})$ \\ \hline $C_{20}\times\triangle T$ \\ Change of m \\ Temperatt \\ Temperatt \\ Temperatu \\ \hline \end{tabular}$: 120Hz±10% (Class 2 : C>1 ce : Change due to Temperature or Rate or is not applied Temperature Compensating (Class1) High Permittivity (Class2) s and Remarks] to of capacitance at 20°C and 85°C, -25°C	Multilayer type Multilayer type (Characteristics: B) Multilayer type (Characteristics: F) shall be made to calculate o 5 (Class 2) step 4:85°C step 5:20°C	: 0.5±0.1Vrms (Class 2: C>10μF) CH: 0±60 SL: -350~+1000 [ppm/C] ±10% +30 -85%

[Test Methods and Remarks]

Apply the stated tensile force progressively in the direction to draw terminal.

Nominal wire diameter [mm]	Tensile force [N]	Duratio[s]
0.45	19.6	5

Torsional			
	Temperature Compensating (Class1)	Multilayer type	
Specified Value	High Permittivity(Class2)	Multilayer type (Characteristics : B)	No at
value	High Permittivity (Class2)	Multilayer type (Characteristics : F)	

abnomalities, such as cuts or looseness of terminals.

[Test Methods and Remarks]

Suspend a mass at the end the terminal, incline the body through angle of 90° and return it to initial position. This operation is done over a period of 5 sec. Then second bend in the opposite direction shall be made.

Nominal wire diameter [mm]	Bending force [N]	Mass weight[kg]
0.45	2.45	0.25

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10. Resistance	e to Vibration			
			Appearance : No significant a	
			Withstanding Voltage: No ab	nomality
			Capacitance:	
				±0.5pF
	Temperature	Multilayer type	5.6pF~8.2pF : Within	
	Compensating (Class1)		10pF or over : Within	
			Q:30pF or under : Q≥40 33pF or over : Q≥10	
			33pF or over : Q≥10 Insulation resistance : 10000	
			C : Nominal Capacitance : [pF	
				•
			Appearance: No significant a Withstanding Voltage: No ab	
			Rated Voltage: 16VDC	Diomaity
			Capacitance : Within ±10%	
			1200pF~22000pF(Item△J)	: Within ±20%
			220000pF~10000000pF	: Within ±10%
			tanδ:	
			1200pF~22000pF(Item△J)	
			220000pF~470000pF	: 5.0% max
			1000000pF~2200000pF	: 7.5% max
			4700000pF~10000000pF	: 12.5% max
			Insulation Resistance : 1200pF~22000pF(Item△J)	: 5000MΩ min
			220000pF	: 500MΩ min
			470000pF	: 200MΩ min
			1000000pF	: 100MΩ min
			2200000pF	: 50MΩ min
			4700000pF~10000000pF	: 20MΩ min
			Rated Voltage : 25VDC	
			Capacitance: Within ±10%	
		Multilayer type (Characteristics : B)	tanδ:	
			1000000pF	: 12.5% max
			Insulation Resistance:	: 00M0
			10000000pF Rated Voltage: 35VDC	: 20MΩ min
			Capacitance: Within ±10%	
			$tan\delta$:	
			1000000pF	: 5.0% max
			2200000pF~4700000pF	: 7.5% max
Specified			Insulation Resistance:	
Value			1000000pF	: 100MΩ min
			2200000pF	: 50MΩ min
			4700000pF	: 20MΩ min
			Rated Voltage: 50VDC	
	High Permittivity (Class2)		Capacitance : Within ±10% tanδ :	
			100pF~39000pF	: 3.5% max
			47000pF~1000000pF	5.0% max
				olo / o max
			Insulation Resistance:	
			100pF~39000pF	: 5000MΩ min
			47000pF~100000pF	: 1000MΩ min
			220000pF	: 500MΩ min
			470000pF	: 200MΩ min
			1000000pF	: 100MΩ min
			Appearance : No significant a	
			Withstanding Voltage: No ab	onomality
			Rated Voltage: 10VDC	
			Capacitance: Within +80 %	
			tanδ:	
			4700000pF~10000000pF	: 17.5% max
			Insulation Resistance:	. 17.370 max
			4700000pF	: 50MΩ min
			10000000pF	: 25MΩ min
			Rated Voltage : 16VDC	
		Multilana trans (Chamatania transcription of	Canacitanae : Within +80 a	
		Multilaver type (Characteristics : E)		
		Multilayer type (Characteristics : F)	Capacitance: Within +80 %	
		Multilayer type (Characteristics : F)	tanδ:	
		Multilayer type (Characteristics : F)	tanδ: 220000pF	: 10.0% max
		Multilayer type (Characteristics : F)	tanδ: 220000pF 470000pF	: 10.0% max
		Multilayer type (Characteristics : F)	tan 5 : 220000pF 470000pF 1000000pF	: 10.0% max : 17.5% max
		Multilayer type (Characteristics : F)	tanδ: 220000pF 470000pF	: 10.0% max
		Multilayer type (Characteristics : F)	tanð: 220000pF 470000pF 1000000pF 2200000pF	: 10.0% max : 17.5% max
		Multilayer type (Characteristics : F)	tanā: 220000pF 470000pF 1000000pF 2200000pF Insulation Resistance:	: 10.0% max : 17.5% max : 15.0% max
		Multilayer type (Characteristics : F)	tanð : 220000pF 470000pF 1000000pF 2200000pF Insulation Resistance : 220000pF	: 10.0% max : 17.5% max : 15.0% max
		Multilayer type (Characteristics : F)	tanð: 220000pF 470000pF 100000pF 2200000pF LInsulation Resistance: 220000pF 470000pF	: 10.0% max : 17.5% max : 15.0% max : 500MΩ min : 500MΩ min
		Multilayer type (Characteristics : F)	tanð : 220000pF 470000pF 1000000pF 2200000pF Insulation Resistance : 220000pF	: 10.0% max : 17.5% max : 15.0% max

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10. Resistanc	e to Vibration			
			Rated Voltage : 25VDC	
			Capacitance: Within +80 %	
			tanō: 10000pF~47000pF(Item△J) Insulation Resistance: 10000pF~47000pF(Item△J)	
			Rated Voltage: 35VDC	
			Capacitance: Within +80 %	
Specified	High Domestic to (Observe)) Multilayer type (Characteristics : F)	tanδ : 10000000pF Insulation Resistance :	:17.5% max
Value	riigir Fermittivity (Glassz)	widitilayer type (Griaracteristics 17)	10000000pF	: 25MΩ min
			Rated Voltage : 50VDC	
			Capacitance: Within +80 %	
			tanδ:	
			10000pF~100000pF	: 7.5% max
			220000pF~470000pF	: 10.0% max
			1000000pF Insulation Resistance:	: 15.0% max
			10000pF~100000pF	: 1000MΩ min
			220000pF~470000pF	: 500MΩ min
			1000000pF	: 250MΩ min

[Test Methods and Remarks]
According to JIS C 5102 clause 8.2
Vibration type: A
Directions: 2 hrs each in X, Y and Z directions
Total: 6 hrs
Frequency range: 10 to 55 to 10Hz (1min)
Amplitude: 1.5 mm
Mounting method: Soldering onto the PC board

44 5 5.11				
11. Free Fall			A	
			Appearance: No significant ab Withstanding Voltage: No abn	
	Temperature Compensating (Class1)	Multilayer type	Capacitance: 4.7pF or under 5.6pF~8.2pF : Within ±0. 10pF or over : Within ±10 Q:30pF or under :33pF or over Q≥1000 Insulation resistance: 10000M C: Nominal Capacitance[pF]	.5pF 0% % 0C
			Appearance : No significant ab	
			Withstanding Voltage: No abn Rated Voltage: 16VDC Capacitance: 1200pF~22000pF(Item△J): 220000pF~10000000pF: With	Within ±20%
	High Permittivity(Class2)	s2) Multilayer type (Characteristics : B)	1000000pF~2200000pF :	3.5% max 5.0% max 7.5% max 12.5% max
Specified Value			470000pF : 1000000pF : 2200000pF : 4700000pF~10000000pF : :	5000ΜΩ min 500ΜΩ min 200ΜΩ min 100ΜΩ min 500ΜΩ min 100ΜΩ min 500ΜΩ min 20ΜΩ min 20ΜΩ min
			Insulation resistance:	12.5% max 20MΩ min
			Rated Voltage : 35VDC Capacitance : Within ±10% tanδ :	
			2200000pF~4700000pF :	5.0% max 7.5% max
				100MΩ min 50MΩ min
				20MΩ min
			Rated Voltage : 50VDC Capacitance : Within±10% tanδ :	
			47000pF~1000000pF :	3.5% max 5.0% max
			47000pF~100000pF :	$5000M\Omega$ min $1000M\Omega$ min
			470000pF :	500MΩ min 200MΩ min 100MΩ min
			тооооорі .	TOOTVISZ TIIIT

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11. Free Fall			
			Appearance : No significant abnomality Withstanding Voltage : No abnomality Rated Voltage : 10VDC Capacitance : Within +80 % tanō :
			4700000pF~1000000pF : 17.5% max Insulation resistance : 4700000pF : 50MΩ min 1000000pF : 25MΩ min
			Rated Voltage : 16VDC Capacitance : Within ±80 %
Specified	High Permittivity (Class2)	Multilayer type (Characteristics : F)	tanδ: 220000pF : 10.0% max 470000pF : 10.0% max 100000pF : 17.5% max 2200000pF : 15.0% max Insulation resistance: 220000pF : 500MΩ min 470000pF : 500MΩ min 1000000pF : 250MΩ min 2200000pF : 125MΩ min Rated Voltage: 25VDC
Value			Capacitance: Within $\frac{+80}{20}$ %
			tan5 : 10000pF~47000pF(Item△J) : 7.5% max Insulation resistance : 10000pF~47000pF(Item△J) : 1000MΩ min
			Rated Voltage: 35VDC
			Capacitance : Within $^{+80}_{-20}$ % tan δ : 10000000pF : 17.5% max Insulation resistance : 10000000pF : 25M Ω min
			Rated Voltage: 50VDC
			Capacitance: Within $\frac{+80}{20}$ %
			tanδ : 10000pF~10000pF :7.5% max 220000pF~470000pF :10.0% max 1000000pF :15.0% max Insulation resistance :
	and Remarks		10000pF ~ 10000pF 1000MΩ min 220000pF ~ 470000pF 500MΩ min 100000pF 250MΩ min 1000000pF 1000000pF 1000000pF 1000000pF 1000000pF 1000000pF 1000000pF 1000000pF 1000000pF 1000000pF 10000000pF 10000000pF 10000000pF 10000000pF 10000000pF 100000000pF 10000000pF 100000000pF 100000000pF 100000000pF 100000000pF 1000000000pF 100000000000000000000000000000000000

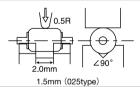
[Test Methods and Remarks] Drop Test : Free fall Impact material : Floor Height : 1 m

Total number of drops : 5 times

12.	Body :	Strenath

-	Specified	Temperature Compensating (Class1)	Multilayer type	
	/alue	High Permittivity (Class2)	Multilayer type (Characteristics : B)	No abnomality such as damage.
			Multilayer type (Characteristics : F)	

[Test Methods and Remarks]
Applied force: 19.6N
Duration: 5 sec.
Speed: Shall attain to specified force in 2 sec.



13. Solderability Temperature Specified

Multilayer type Compensating (Class1) Multilayer type (Characteristics : B) High Permittivity (Class2) Multilayer type (Characteristics : F)

At least 75% of lead surface is covered with new solder.

Value

[Test Methods and Remarks]
Solder temperature: 230±5°C
Duration: 2±0.5 sec. (This test may be applicable after 6 months storage.)

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

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			Appearance : No significant abnomality Withstanding Voltage : No abnomality
	Temperature Compensating (Class1)	Multilayer type	Capacitance change: 8.2pF or under : Within ±0.25pF 10pF or over : Within ±2.5% Q:30pF or under Q≥400+20C :33pF or over Q≥1000 Insulation resistance: 10000MΩ min. C: Nominal Capacitance[pF]
Specified /alue	High Permittivity(Class2)	Multilayer type (Characteristics : B)	Appearance : No significant abnomality Withstanding Voltage : 16VDC
		Multilayer type (Characteristics : F)	Appearance : No significant abnomality Withstanding Voltage : No abnomality Rated Voltage : 10 VDC Capacitance change : Within $\pm 20\%$ $tan\delta$: $4700000pF \sim 10000000pF$: 17.5% max Insulation resistance : $4700000pF = 50M\Omega$ min $1000000pF = 25M\Omega$ min Rated Voltage : 16 VDC Capacitance change : Within $\pm 20\%$ $tan\delta$: $220000pF \sim 470000pF = 10.0\%$ max $1000000pF = 17.5\%$ max $2200000pF \sim 17.5\%$ max $220000pF \sim 17.5\%$ max $220000pF \sim 17.5\%$ max Insulation resistance : $220000pF \sim 470000pF = 500M\Omega$ min $1000000pF = 250M\Omega$ min $2200000pF \sim 125M\Omega$ min Rated Voltage : 25 VDC Capacitance change : Within $\pm 20\%$ $tan\delta$: $10000pF \sim 47000pF$ (Item \triangle J) : 7.5% max Insulation resistance :

Withstanding voltage is also referred to as "voltage proof" under IEC specifications. Thermal Shock is also referred to as "rapid change of temperature" under IEC specifications.

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$Specified Value \begin{tabular}{lll} Permittivity (Class2) & Part & Pa$	14. Soldering				
Insulation resistance :	Specified	High Permittivity (Class2)	Multilayer type (Characteristics : F)	Capacitance change:\\\ tan\(\delta\):\\ 10000000pF\\ Insulation resistance:\\ 1000000pF\\ Rated Voltage:50VDC\\ Capacitance change:\\ 10000pF\(^100000pF\) 10000pF\(^100000pF\) 100000pF\(^100000pF\) 100000pF\(^100000pF\) Insulation resistance:\\ 10000pF\(^100000pF\) 220000pF\(^100000pF\) 220000pF\(^100000pF\) 220000pF\(^100000pF\)	Within ±20% : 17.5% max : 25MΩ min : Within ±20.0% : 7.5% max : 10.0% max : 15.0% max : 1000MΩ min : 500MΩ min

[Test Methods and Remarks] Solder temperature: 270±5°C Duration: 5±0.5 sec.

Duration: 5±0.5 sec. Immersed conditions: Inserted into the PC board (with t=1.6mm, hole=1.0mm diameter)

Preconditioning: 1 hr of preconditioning at 150 $^{+0}_{-10}$ °C followed by 48±4 hrs of recovery under the standard condition. Recovery: Recovery for the following period under the standard condition after the test. 24±2 hrs (Class 1) 48±4 hrs (Class 2)

Resistance	to Solvent		
Specified	Temperature Compensating (Class1)	Multilayer type	
Value	High Permittivity (Class2)		No significant abnormality in appearance and legible marking.
	night Fermittivity (Class2)	Multilayer type (Characteristics : F)	

[Test Methods and Remarks] According to JIS C 5102 clause 8.7.4. Type of test: Method 1 Solvent temperature : 20 to 25℃

Duration: 30±5 sec.
Solvent Type: A in Table 23, Isopropyl alcohol

16. Thermal SI	hock		
			Appearance: No significant abnomality Withstanding Voltage: No abnomality
	Temperature Compensating (Class1)	Multilayer type	Capacitance change : 8.2pF or under : Within $\pm 0.5pF$ 10pF or over : Within $\pm 5.0\%$ Q : 8.2pF or under Q \geq 200+10C : 10pF \sim 30pF Q \geq 275+2.5C : 33pF or over Q \geq 350 Insulation resistance : 1000M Ω or over C : Nominal Capacitance[pF]
Specified Value	High Permittivity (Class2)	Multilayer type (Characteristics : B)	Appearance : No significant abnomality Withstanding Voltage : No abnomality Rated Voltage : 16VDC Capacitance change : 1200pF~22000pF (Item△J) : Within ±12.5% 220000pF~10000000pF : Within ±15.0% tanδ : 1200pF~22000pF (Item△J) : 5.0% max 220000pF~470000pF : 7.5% max 100000pF~2200000pF : 10.0% max 4700000pF~10000000pF : 22.5% max Insulation resistance : 1200pF~22000pF (Item△J) : 1000MΩ min 220000pF : 125MΩ min 470000pF : 50MΩ min 1000000pF : 25MΩ min 1200000pF : 12.5MΩ min 4700000pF~10000000pF : 5MΩ min 4700000pF~10000000pF : 5MΩ min 4700000pF~10000000pF : 5MΩ min
			2200000pF : 25MΩ min 470000pF : 5MΩ min

Withstanding voltage is also referred to as "voltage proof" under IEC specifications. $Thermal\ Shock\ is\ also\ referred\ to\ as\ "rapid\ change\ of\ temperature"\ under\ IEC\ specifications.$

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16. Thermal St	nock			
			Rated Voltage: 50VDC Capacitance change: 100pF~39000pF	: Within ±12.5%
		Multilayer type (Characteristics : B)	47000pF~1000000pF tanδ: 100pF~39000pF 47000pF~1000000pF	: Within ±15.0% : 5.0% max : 7.5% max
		Multilayer type (Grialacteristics - B)	Insulation resistance: 100pF~3900pF 47000pF~100000pF 220000pF 470000pF 1000000pF	: 1000MΩ min : 500MΩ min : 250MΩ min : 100MΩ min : 500MΩ min
			Appearance : No significant a Withstanding Voltage : No abi	
			Rated Voltage : 10VDC Capacitance change	: Within ±30.0%
			tanδ : 4700000pF∼10000000pF : 2l	0.0% max
			Insulation resistance : 4700000pF 10000000pF	: 10MΩ min : 5MΩ min
			Rated Voltage: 16VDC Capacitance change	: Within ±30.0%
Specified Value	High Permittivity(Class2)		tanδ: 220000pF∼470000pF 1000000pF 2200000pF	: 15.0% max : 22.5% max : 17.5% max
			Insulation resistance : 220000pF 470000pF 1000000pF 2200000pF	: 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min
		Multilayer type (Characteristics : F)	Rated Voltage : 25VDC Capacitance change tanδ :	: Within ±30%
			10000pF~47000pF(Item△J) Insulation resistance: 10000pF~47000pF(Item△J)	
			Rated Voltage : 35VDC Capacitance change tanδ:	: Within ±30.0%
			1000000pF Insulation resistance:	: 20.0% max
			10000000pF Rated Voltage: 50VDC Capacitance change: 10000pF~1000000pF	: $5M\Omega$ min : Within $\pm 30.0\%$
			tanδ∶ 10000pF~100000pF 220000pF~470000pF 1000000pF	: 12.5% max : 15.0% max : 17.5% max
			Insulation resistance : 10000pF~100000pF 220000pF~470000pF 1000000pF	: 500MΩ min : 250MΩ min : 50MΩ min

[Test Methods and Remarks] Conditions for 1 cycle

,		
Step	Temperature [°C]	Duration [min.]
1	Room temperature	Within 3
2	-25±3	30±3
3	Room temperature	Within 3
4	+85±3	30±3
5	Room temperature	Within 3

Number of cycles: 5

Preconditioning : 1 hr of preconditioning at 150 $^{+0}_{-10}$ °C followed by 48±4 hrs of recovery under the standard condition. Recovery: Recovery for the following period under the standard condition after the removal from test chamber. 24±2 hrs (Class 1) 48±4 hrs (Class 2)

Withstanding voltage is also referred to as "voltage proof" under IEC specifications. Thermal Shock is also referred to as "rapid change of temperature" under IEC specifications.

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17. Damp Hea	t (steady state)		
Samp 116a	Temperature Compensating (Class1)	Multilayer type	Appearance : No significant abnomality Withstanding Voltage : No abnomality Capacitance change : 8.2pF or under : Within $\pm 0.5pF$ 10pF or over : Within $\pm 5.0\%$ Q : 8.2pF or under Q $\geq 200+10C$: $10pF-30pF$ Q $\geq 275+2.5C$: $33pF$ or over Q ≥ 350 Insulation resistance : $1000M\Omega$ min C : Nominal Capacitance [pF]
Specified Value	High Permittivity (Class2)	Multilayer type (Characteristics : B)	Appearance : No significant abnomality Withstanding Voltage : No abnomality Rated Voltage : 16VDC Capacitance change : 1200pF~22000pF (ItemΔJ) : Within ±12.5% 220000pF~1000000pF : Within ±15.0% tanδ : 1200pF~22000pF (ItemΔJ) : 5.0% max 22000pF~470000pF : 10.0% max 4700000pF~10000000pF : 10.0% max 4700000pF~220000pF (ItemΔJ) : 1000MΩ min 220000pF : 125MΩ min 470000pF : 125MΩ min 470000pF : 125MΩ min 470000pF : 15.0% max 1700000pF : 15.0% max 1700000pF : 15.0% max 17000000pF : 10.0% max 17000000pF : 10.0% max 17000000pF : 10.0% max 17000000pF : 10.0% max 17000000pF : 10.0% max 17000000pF : 25MΩ min
		Multilayer type (Characteristics : F)	Appearance : No significant abnomality Withstanding Voltage : No abnomality

With standing voltage is also referred to as "voltage proof" under IEC specifications.

47 D II	1/1 1 1 1			
17. Damp Hea	at (steady state)			
			Rated Voltage:25VDC Capacitance change	: Within ±30%
			tanδ: 10000pF~47000pF(Itemalinsulation resistance: 10000pF~47000pF(Itemalinsulation)	
		Multilayer type (Characteristics : F)	Rated Voltage : 35VDC Capacitance change tanδ:	: Within ±30.0%
Specified			10000000pF Insulation resistance:	: 20.0% max
Value	High Permittivity (Class2)		10000000pF	÷5MΩ min
			Rated Voltage:50VDC Capacitance change:	
			10000pF~1000000pF tanδ:	: Within ±30.0%
			10000pF~100000pF	: 12.5% max
			220000pF~470000pF	: 15.0% max
			1000000pF Insulation resistance:	: 17.5% max
			10000pF~100000pF	: 500MΩ min
			220000pF~470000pF	: 250MΩ min
			1000000pF	: 50MΩ min

	under Damp Heat		ory andor the standard seria	d condition. 1) Ition after the removal from chamber. (Class 2)
	Temperature Compensating (Class1)	Multilayer type	Appearance: No significant Withstanding Voltage: No a Capacitance change: 8.2pF or under : Within 10pF or over : Within Q:30pF or under Q≧100-:33pF or over Q≧200 Insulation resistance: 500M C: Nominal Capacitance[p	±0.75pF ±7.5% ±7.5% ±7.93°C
Specified /alue	High Permittivity (Class2)	Multilayer type (Characteristics : B)	Appearance: No significant Withstanding Voltage: No a Rated Voltage: 16VDC Capacitance change: 1200pF~22000pF~470000pF 1000000pF~100000pF~100000pF~100000pF~100000pF~100000pF~100000pF~100000pF~100000pF~100000pF~12000pF~220000pF~120000pF~120000pF~120000pF~120000pF~120000pF~120000pF~120000pF~120000pF~120000pF~120000pF~1000000pF~1200000pF~10000000pF~1000000pF~1000000pF~1000000pF~1000000pF~1000000pF~1000000pF~10000000pF~1000000pF~1000000pF~1000000pF~1000000pF~10000000pF~1000000pF~1000000pF~1000000pF~1000000pF~1000000pF~1000000pF~10000000pF~10000000pF~10000000pF~10000000pF~10000000pF~10000000pF~10000000000	D): Within ±12.5% : Within ±15.0% : Within ±22.5% J): 5.0% max : 7.5% max : 10.0% max : 22.5% max

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

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ro. Louding a	nder Damp Heat			
			Appearance : No significant Withstanding Voltage : No a	
			Rated Voltage : 10VDC Capacitance change tanδ :	: Within ±30.0%
			4700000pF~1000000pF Insulation resistance:	: 20.0% max
			4700000pF 10000000pF	: 5M Ω min : 2.5M Ω min
			Rated Voltage : 16VDC Capacitance change tanδ :	: Within ±30.0%
			220000pF~470000pF 1000000pF	: 15.0% max : 22.5% max
			2200000pF Insulation resistance:	: 17.5% max
			220000pF 470000pF	: 50MΩ min : 25MΩ min
			1000000pF 2200000pF	: 12.5MΩ min : 12.5MΩ min
pecified alue	High Permittivity (Class2)	Multilayer type (Characteristics : F)	Rated Voltage : 25VDC Capacitance change tanδ :	: Within ±30.0%
			10000pF~47000pF(Item△ Insulation resistance:	3J): 12.5% max
			10000pF~47000pF(Item△	ΔJ): 250MΩ min
			Rated Voltage : 35VDC Capacitance change : tanδ :	Within ±30.0%
			1000000pF Insulation resistance:	: 20.0% max
			10000000pF	: 2.5MΩ min
			Rated Voltage : 50VDC Capacitance change : 10000pF~1000000pF tanδ :	∶ Within ±30.0%
			10000pF~100000pF	: 12.5% max
			220000pF~470000pF	: 15.0% max
			1000000pF Insulation resistance:	:17.5% max
			10000pF~100000pF	: 250MΩ min
			220000pF~470000pF	: 125M $Ω$ min
			1000000pF	: 25MΩ min
Test Methods emperature : lumidity : 90 t				
uration : 500 pplied voltag	+24 -0 hrs e: Rated voltage	+0 00 4 11		
ecovery : 24	±2 hrs of recovery under to	he standard condition after the remo	val from test cham-ber. (Clas	ss 1)
Duration: 500 Applied voltag Preconditionin Recovery: 24	+24/hrs e:Rated voltage g:1 hr of preconditioning a ±2 hrs of recovery under the	at 150 $^{+0}_{-10}$ °C followed by 48 \pm 4 hrs c he standard condition after the remo $^{+0}_{-10}$ °C followed by 48 \pm 4 hrs of reco	val from test cham-ber. (Clas	rd condition. ss 1) dition after the removal from chamber. (Class 2)

19. High Temp	perature Lading Test		
	Temperature Compensating (Class1)	Multilayer type	Appearance : No significant abnomality Withstanding Voltage : No abnomality Capacitance change : 8.2pF or under : Within $\pm 0.3pF$ 10pF or over : Within $\pm 3.0\%$ Q : 8.2pF or under : 10pF-30pF : 33pF or over : 33pF or over 33pF or over 33pF or over 0≥275+2.5C 33pF or over 0≥350 1000MΩ min C : Nominal Capacitance[pF]
Specified Value	High Permittivity (Class2)	Multilayer type (Characteristics : B)	Appearance : No significant abnomality Withstanding Voltage : No abnomality Rated Voltage : 18VDC Capacitance change : 1200pF~22000pF (Item△J) : Within ±12.5% 220000pF~470000pF : Within ±15.0% 1000000pF~10000000pF : Within ±22.5% tanδ : 1200pF~220000pF (Item△J) : 5.0% max 220000pF~470000pF : 17.5% max 100000pF~2200000pF : 10.0% max 4700000pF~10000000pF : 22.5% max Insulation resistance : 1200pF~22000pF (Item△J) : 1000MΩ min 220000pF : 125MΩ min 4700000pF : 50MΩ min 100000pF : 25MΩ min 1200000pF : 12.5MΩ min 4700000pF : 12.5MΩ min 4700000pF : 12.5MΩ min 1200000pF : 12.5MΩ min 14700000pF : 12.5MΩ min 14700000pF : 12.5MΩ min 14700000pF : 12.5MΩ min 14700000pF : 12.5MΩ min

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

	erature Lading Test	T	T	
			Rated Voltage: 25VDC Capacitance change:	
			Capacitatice charige :	
			1000000pF	: Within ±22.5%
			tanδ: 10000000pF	: 22.5% max
			Insulation resistance:	. 22.370 IIIaX
			1000000pF	: 5MΩ min
			Rated Voltage: 35VDC	
			Capacitance change: 1000000pF	: Within +15 00/
			2200000pF	: Within ±15.0% : Within ±15.0%
			4700000pF	: Within ±22.5%
			tanδ : 1000000pF	: 10.0% max
			2200000pF~4700000pF	: 10.0% max
		Multilayer type (Characteristics : B)	Insulation resistance:	
			1000000pF	: 25MΩ min
			2200000pF 4700000pF	: 25M Ω min : 5M Ω min
			Rated Voltage : 50VDC	- CHILL THIN
			Capacitance change:	
			100pF~39000pF	: Within ±12.5%
			47000pF~1000000pF tanδ:	: Within ±15.0%
			100pF~39000pF	: 5.0% max
			47000pF~1000000pF	: 7.5% max
			Insulation resistance: 100pF~39000pF	: 1000MΩ min
			47000pF~100000pF	: 500MΩ min
			220000pF	: 250MΩ min
			470000pF 1000000pF	: 100MΩ min : 50MΩ min
			Appearance : No significan	
			Withstanding Voltage: No a	
			Rated Voltage: 10VDC	
Specified			Capacitance change tanδ:	: Within ±30.0%
Value	High Permittivity (Class2)	2)	4700000pF~10000000pF	: 20.0% max
			Insulation resistance:	
			4700000pF 10000000pF	: 10MΩ min : 5MΩ min
			Rated Voltage: 16VDC	· OWIZZ THIIT
			Capacitance change	: ±30%
			tanδ: 220000pF~470000pF	:15.0% max
			220000pr. 9470000pr	
				: 22.5% max
			1000000pF 2200000pF	
			1000000pF 2200000pF Insulation resistance:	: 22.5% max : 17.5% max
			1000000pF 2200000pF Insulation resistance: 220000pF	: 22.5% max
			100000pF 220000pF Insulation resistance: 22000pF 470000pF 1000000pF	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min
			100000pF 220000pF Insulation resistance : 220000pF 470000pF 1000000pF 2200000pF	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min
		Multilaver type (Characteristics : F)	100000pF 220000pF Insulation resistance : 220000pF 470000pF 1000000pF 2200000pF Rated Voltage : 25VDC	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanő:	: 22.5% max : 17.5% max : 100M Ω min : 50M Ω min : 25M
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanð: 10000pF~47000pF(Item△	: 22.5% max : 17.5% max : 100M Ω min : 50M Ω min : 25M
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanδ: 10000pF~47000pF(Item△ Insulation resistance:	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanδ: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 22000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanð: 10000pF~47000pF (Item△ Insulation resistance: 10000pF~47000pF (Item△ Rated Voltage: 35VDC Capacitance change	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 22000pF 47000pF 100000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanδ: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Capacitance change: 35VDC Capacitance change tanδ:	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max ΔJ): 500MΩ min : Within ±30.0%
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 22000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanð: 10000pF~47000pF (Item△ Insulation resistance: 10000pF~47000pF (Item△ Rated Voltage: 35VDC Capacitance change	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanð: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanð: 100000pF~47000pF(Item△ 100000pF~47000pF(Item△ 1000000pF~47000pF(Item△ 10000000pF~47000pF(Item△ 10000000pF~47000pF(Item△	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max ΔJ): 500MΩ min : Within ±30.0%
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 22000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanδ: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanδ: 1000000pF Insulation resistance: 10000000pF Insulation resistance: 10000000pF Insulation resistance: 10000000pF Insulation resistance: 10000000pF Insulation resistance:	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% AJ): 10.0% max AJ): 500MΩ min : Within ±30.0% : 20.0% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanδ: 1000000pF Insulation resistance: 10000000pF Rated Voltage: 35VDC Capacitance change tanδ: 10000000pF Insulation resistance: 10000000pF Rated Voltage: 50VDC Capacitance change:	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min : 25MΩ min : Within ±30% ΔJ): 10.0% max ΔJ): 500MΩ min : Within ±30.0% : 20.0% max : 5MΩ min
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 22000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanδ: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanδ: 1000000pF Insulation resistance: 10000000pF Insulation resistance: 10000000pF Insulation resistance: 10000000pF Insulation resistance: 10000000pF Insulation resistance:	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% AJ): 10.0% max AJ): 500MΩ min : Within ±30.0% : 20.0% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanð: 100000pF~47000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF 100000pF 100000pF 100000pF 100000pF 100000pF	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min : 25MΩ min : Within ±30% ΔJ): 10.0% max ΔJ): 500MΩ min : Within ±30.0% : 20.0% max : 5MΩ min
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanð: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 100000pF 1000000pF 100000pF 100000pF 10000pF~4700000pF 220000pF~470000pF	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max : Within ±30.0% : 20.0% max : 5MΩ min : Within 30.0% : 10.0% max : 10.0% max : 12.5% max
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanð: 10000pF~47000pF(Item△ Insulation resistance: 100000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanð: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 1000000pF 1000000pF 1000000pF 1000000pF 200000pF~100000pF tanð: 10000pF~100000pF 220000pF~470000pF	: 22.5% max : 17.5% max : 100MΩ min : 50MΩ min : 25MΩ min : 25MΩ min : 25MΩ min : Within ±30% ΔJ): 10.0% max ΔJ): 500MΩ min : Within ±30.0% : 20.0% max : 5MΩ min
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanð: 1000000pF Insulation resistance: 1000000pF Rated Voltage: 55VDC Capacitance change tanð: 1000000pF Insulation resistance: 100000pF~100000pF 10000pF~100000pF tanð: 10000pF~100000pF 100000pF Insulation resistance: 10000pF~100000pF 100000pF 100000pF Insulation resistance: 10000pF~100000pF	: 22.5% max : 17.5% max : 100MΩ min : 25MΩ min : 25MΩ min : 25MΩ min Within ±30% ΔJ): 10.0% max : Within ±30.0% : 20.0% max : 5MΩ min : Within 30.0% : 10.0% max : 17.5% max : 17.5% max : 500MΩ min
		Multilayer type (Characteristics : F)	100000pF 220000pF Insulation resistance: 220000pF 470000pF 47000pF 1000000pF 2200000pF Rated Voltage: 25VDC Capacitance change: tanð: 10000pF~47000pF(Item△ Insulation resistance: 10000pF~47000pF(Item△ Rated Voltage: 35VDC Capacitance change tanð: 1000000pF Insulation resistance: 1000000pF Insulation resistance: 100000pF~100000pF Tated Voltage: 50VDC Capacitance change: 10000pF~100000pF 10000pF~100000pF 220000pF~170000pF 100000pF	: 22.5% max : 17.5% max : 100MΩ min : 25MΩ min : 25MΩ min : 25MΩ min : 25MΩ min : Within ±30% ΔJ): 10.0% max : Within ±30.0% : 20.0% max : 5MΩ min : Within 30.0% : 10.0% max : 12.5% max : 17.5% max

[Test Methods and Remarks]

[Test Methods and Remarks]
Temperature: 85± $\frac{3}{6}$ °C
Duration: 1000± $\frac{48}{6}$ hrs
Applied voltage: Rated voltage×2
: Rated voltage×1.5
Class 2: B 1000000pF (025Type)
B 220000pF~1000000pF (050Type, 075Type)

Preconditioning: 1 hr of preconditioning at 150 $\frac{110}{6}$ °C followed by 48±4 hrs of recovery under the standard condition.

Recovery: 24±2hrs of recovery under the standard condition after the removal from test chamber. (Class 1)
: 1 hr of preconditioning at 150 $\frac{110}{6}$ °C followed by 48±4 hrs of recovery under the standard condition after the removal from test chamber. (Class 1)

Note on standard condition: "standard condition" referred to herein is defined as follows:

5 to 35°C of temperature, 45 to 85% relative humidity, and 86 to 106kPa of air pressure.

When there are questions concerning measurement results: In order to provide correlation data, the test shall be conducted under condition of 20±2°C of temperature, 60 to 70% relative humidity,

and 86 to 106kPa of air pressure. Unless otherwise specified, all the tests are conducted under the "standard condition." Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

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Circuit Design

- ◆Verification of operating environment, electrical rating and performance
- 1.A malfunction in medical equipment, spacecraft, nuclear reactors, etc. may cause serious harm to human life or have severe social ramifications. As such, any capacitors to be used in such equipment may require higher safety and/or reliability considerations and should be clearly differentiated from components used in general purpose applications.
- ◆Verification of Rated voltage (DC rated voltage)
- 1. The operating voltage for capacitors must always be lower than their rated values.

 If an AC voltage is loaded on a DC voltage, the sum of the two peak voltages should be lower than the rated value of the capacitor chosen. For a circuit where both an AC and a pulse voltage may be present, the sum of their peak voltages should also be lower than the capacitor's rated voltage Self-generated heat (Verification of Temperature)

Precautions

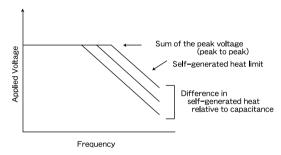
- Is the capacitors specified only for DC use are used in AC or pulse circuits, the AC or a pulse current can generate heat inside the capacitor so the self-generated temperature rise should be limited to within 20°C. The surface temperature measured should include this self-temperature rise. Therefore, it is required to limit capacitor surface temperature including self-generated heat should not exceed the maximum operating temperature of +85°C.
- Operating Environment precautions

 1. Capacitors should not be used in the following environments:
 - (1) Environmental conditions to avoid
 - a exposure to water or salt water
 - b. exposure to moisture or condensation.
 - c. exposure to corrosive gases (such as hydrogen sulfide, sulfurous acid, chlorine, and ammonia)
- When an AC or a pulse voltage is applied to capacitors specified for DC use, even if the voltage is less than the rated voltage, the AC current or pulse current running through the capacitor will cause the capacitor to self-generate heat because of the loss characteristics.

 The amount of heat generated depends on the dielectric materials used, capacitance, applied voltage, frequency, voltage waveform, etc. The surface
- temperature changes due to emitted heat which differs by capacitor shape or mounting method.

 Please contact Taiyo Yuden with any questions regarding emitted heat levels in your particular application. It is recommended the temperature rise be
- measured in the actual circuit to be used.
- 1-2. For capacitors, the voltage and frequency relationship is generally determined by peak voltage at low frequencies, and by self-generated heat at high frequencies. (Refer to the following curve.)

Technical consider ations



2. PCB Design

Design of the capacitor mount

Precautions

1. When capacitors are mounted onto a PC board, hole dimensions on the board should match the lead pitch of the component, if not it will cause breakage of the terminals or cracking of terminal roots covered with resin as excess stress travels through the terminal legs. As a result, humidity resistance performance would be lost and may lead to a reduction in insulation resistance and cause a withstand voltage failure.

3. Considerations for automatic insertion

Precautions

Adjustment Automatic Insertion machines (leaded components)

1. When inserting capacitors in a PC board by auto-insertion machines the impact load imposed on the capacitors should be minimized to prevent the leads from chucking or clinching.

Technical conside ations

- When installing products, care should be taken not to apply distortion stress as it may deform the products.
 Our company recommends the method to place the lead with fewer loads that join the product.

4. Soldering

◆Selection of Flux

- 1. When soldering capacitors are on the board, flux should be applied thinly and evenly.
- Flux used should be with less than or equal to 0.1 wt% (equivalent to Chroline) of halogenated content. Flux having a strong acidity content should not be applied.
- When using water-soluble flux, special care should be taken to properly clean the boards.

Temperature, time, amount of solder, etc. are specified in accordance with the following recommended conditions.

Precautions

- 2. Do not immerse the entire capacitor in the flux during the soldering operation. Only solder the lead wires on the bottom of the board.
- ◆Recommended conditions for using a soldering iron:
- 1. Put the soldering iron on the land-pattern
 - Soldering iron's temperature below 350°C Duration 3 seconds or less
 - Numbers of times 1 times
 - The soldering iron should not directly touch the capacitor.

Selection of Flux

- 1. Flux is used to increase solderability in wave soldering, but if too much is applied, a large amount of flux gas may be emitted and may detrimentally affect solderability. To minimize the amount of flux applied, it is recommended to use a flux-bubbling system.
- 2. With too much halogenated substance (Chlorine, etc.) content is used to activate the flux, an excessive amount of residue after soldering may lead to corrosion of the terminal electrodes or degradation of insulation resistance on the surface of the capacitors.
- 3. Since the residue of water-soluble flux is easily dissolved by water content in the air, the residue on the surface of capacitors in high humidity conditions may cause a degradation of insulation resistance and therefore affect the reliability of the components. The cleaning methods and the capability of the machines used should also be considered carefully when selecting water-soluble flux.

Technical considerations

♦Wave Soldering

- 1. If capacitors are used beyond the range of the recommended conditions, heat stresses may cause cracks inside the capacitors, and consequently degrade the reliability of the capacitors.
- 2. When the capacitors are dipped in solder, some soldered parts of the capacitor may melt due to solder heat and cause short-circuits or cracking of the ceramic material. Deterioration of the resin coating may lower insulation resistance and cause a reduction of withstand voltage.
- ◆Recommended conditions for using a soldering iron:
- 1. If products are used beyond the range of the recommended conditions, heat stress may deform the products, and consequently degrade the reliability of the products.

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PRECAUTIONS

5. Cleaning

Precautions

◆Board cleaning

1. When cleaning the mounted PC boards, make sure that cleaning conditions are consistent with prescribed usage conditions.

Technical considerThe resin material used for the outer coating of capacitors is occasionally a wax substance for moisture resistance which can easily be dissolved by some solutions. So before cleaning, special care should be taken to test the component's vulnerability to the solutions used.

When using water-soluble flux please clean the PCB with purified water sufficiently and dry thoroughly at the end of the process. Insufficient washing or drying could lower the reliability of the capacitors.

6. Post-cleaning-process

 Application of resin molding, etc. to the PCB and components.
 Please contact your local Taiyo Yuden sales office before performing resin coating or molding on mounted capacitors. Please verify on the actual application that Precautions

the coating process will not adversely affect the component quality.

- The thermal expansion and coefficient of contraction of the molded resin are not necessarily matched with those of the capacitor. The capacitors may be exposed to stresses due to thermal expansion and contraction during and after hardening. This may lower the specified characteristics and insulation resistance or cause reduced withstanding voltage by cracking the ceramic or separating the coated resin from the ceramics.
- With some types of mold resins, the resin's decomposition gas or reaction gas may remain inside the resin during the hardening period or while left under normal conditions, causing a deterioration of the capacitor's performance.
- 1-3. Some mold resins may have poor moisture proofing properties. Please verify the contents of the resins before they are applied.
- 1-4. Please contact Taiyo Yuden before using if the hardening process temperature of the mold resins is higher than the operating temperature of the capacitors

7. Handling

Technical

consider-

ations

Mechanical considerations

Precautions

- 1. Be careful not to subject the capacitors to excessive mechanical shocks. Withstanding voltage failure may result.
- 2. If ceramic capacitors are dropped onto the floor or a hard surface they should not be used

Technical considerations

- Because the capacitor is made of ceramic, mechanical shocks applied to the board may damage or crack the capacitors.
- 2. Ceramic capacitors which are dropped onto the floor or a hard surface may develop defects and have a higher risk of failure over time.

8. Storage conditions

Storage

Precautions

- 1. To maintain the solderability of terminal electrodes and to keep the packaging material in good condition, care must be taken to control temperature and humidity in the storage area. Humidity should especially be kept as low as possible. Recommended conditions: Ambient temperature Below 40 °C Humidity Below 70% RH. Products should be used within 6 months after delivery. After the above period, the solderability should be checked before using the capacitors.
- 2. Capacitors should not be kept in an environment filled with decomposition gases such as sulfurous hydrogen, sulfurous acid, chlorine, ammonia, etc
- 3. Capacitors should not be kept in a location where they may be exposed to moisture, condensation or direct sunlight.

Technical considerations

Under high temperature/high humidity conditions, the decrease in solderability due to the oxidation of terminal electrodes and deterioration of taping and packaging characteristics may be accelerated.

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